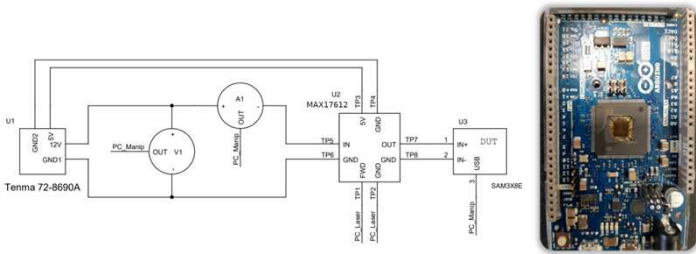


I. Context

- Single event latch-up results in high current events in an electrical component
- High current events can damage and compromise various functions of a microcontroller
- Small high current events are complex to detect
- Data based approaches and machine learning can improve high current event detection.

II. Experimental tests

- Laser tests to get high current event data
- On Atmel SAM3X microcontroller
- At CNES France

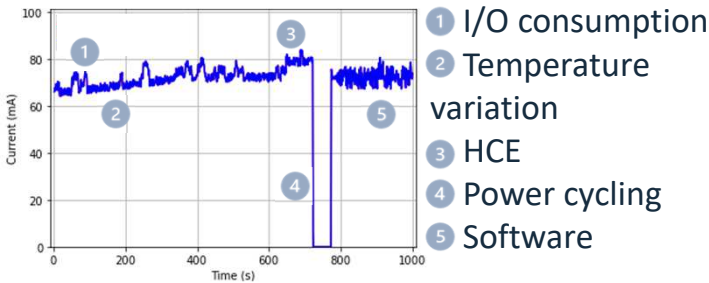


III. Simulation framework

- Simulated data created

$$I(t) = (f_{Nominal}(t, \bar{I}) + \sum_i f_{Load_i}(t, l_i, t_i, d_i) + \sum_j f_{Soft_j}(t, s_j, t_j, d_j) + \sum_k f_{Temp_k}(t, a_k, t_k, d_k) + \sum_l f_{HCE_l}(t, f_l, t_l, r_l)) * \sum_m f_{Reset_m}(t, t_m, d_m)$$

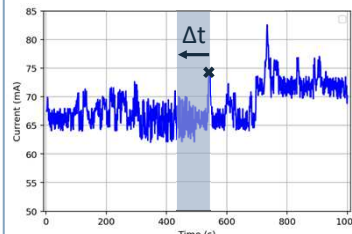
- Various current profile scenarios possible



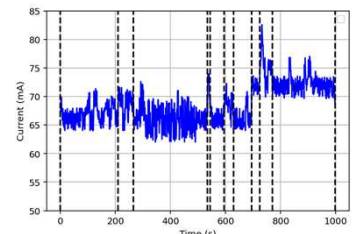
IV. Pre-processing

- Two time window methods tested

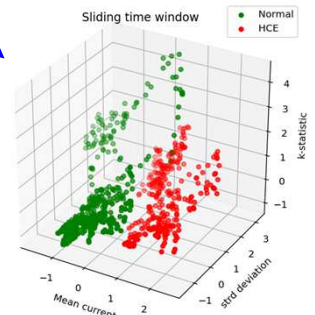
Sliding time window



Rupture time window

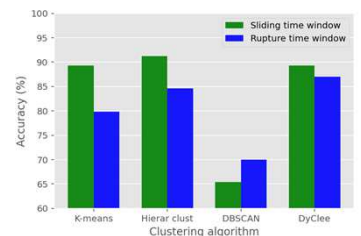
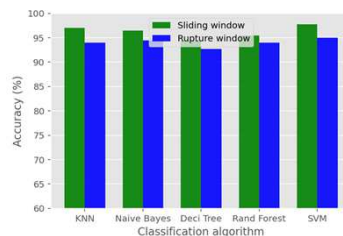


- Feature extraction with statistical calculations created with both normal and abnormal data



V. Detection results

- Classification and clustering



VI. Conclusion

Using both experimental tests and simulation, a method to gather consumption current data set is proposed. Then, various machine learning algorithms are tested to detect high current events. With overall results between 85% and 97% detection accuracy, this method improves small high current event detection that are normally imperceptible with today's threshold detection.

